



SIGNAL PROCESSING EXCELLENCE

SP-2510/12/15

High Slew Rate Operational Amplifiers

T-79-07-10

Features

- 65 V/ μ S Slew Rate
- 250 nS Settling Time to 0.1%
- 1 MHz Full Power Bandwidth
- 12 MHz Gain Bandwidth
- 100 M Ω Input Impedance
- Internally Compensated

Applications

- Video Amplifiers
- Pulse Amplifiers
- Signal Generators
- High Speed Sample-and-Hold Amplifiers

Description

The SP-2510/12/15 operational amplifiers are optimally compensated for bandwidth, slew rate, and settling time. These characteristics make these devices the preferred candidates for high accuracy and high frequency analog signal processing applications.

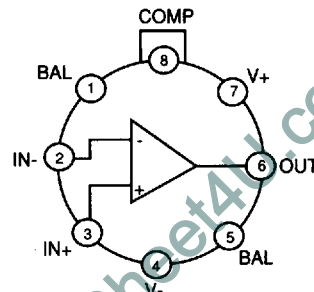
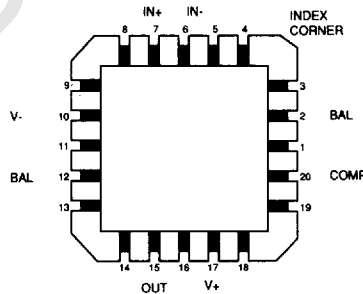
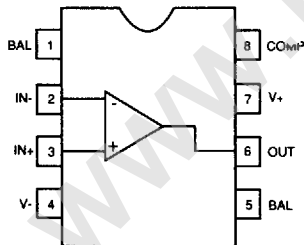
These devices are designed to allow additional compensation and offset trimming. A 100K Ω trim potentiometer is recommended for use between the balance pins (the wiper should be connected to V⁺).

The SP-2512 and SP-2515 are the relaxed specification military temperature range and the commercial temperature range of the SP-2510.

All versions are available in metal can, ceramic mini DIP packages, and in die form. The SP-2510 is also available in ceramic LCC packages.

4

Connection Diagrams



SP-2510/12/15

High Slew Rate Operational Amplifiers

Absolute Maximum Ratings

| | | | |
|---|--------|-----------------------------|--------------------------------|
| Voltage Between V ⁺ and V ⁻ Terminals | 40.0V | Operating Temperature Range | |
| Differential Input Voltage, V _d | ±15.0V | SP-2510 | -55°C ≤ T _A ≤ 125°C |
| Internal Power Dissipation, P _d | 300mW | Storage Temperature Range | -65°C ≤ T _A ≤ 150°C |
| Peak Output Current, I _p | 50mA | | |

Electrical Characteristics: V⁺ = +15V, V⁻ = -15V, T_A = 25°C unless otherwise specified in "Conditions".

SP-2510

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|---------------------------------|----------------------|--|-------|-------|-----|-------|
| Input Characteristics | | | | | | |
| Offset Voltage | V _{OS} | -55°C ≤ T _A ≤ 125°C | | 4 | 8 | mV |
| Offset Voltage Drift | ΔV _{OS} /ΔT | -55°C ≤ T _A ≤ 125°C; average | | 20 | 11 | μV/°C |
| Bias Current | I _B | -55°C ≤ T _A ≤ 125°C | | 100 | 200 | nA |
| Offset Current | I _{OS} | -55°C ≤ T _A ≤ 125°C | | 10 | 25 | nA |
| Input Impedance | Z _{in} | Guaranteed by Design | 50 | 100 | | MΩ |
| Common Mode Range | V _{cm} | -55°C ≤ T _A ≤ 125°C | ±10.0 | | 50 | V |
| Transfer Characteristics | | | | | | |
| Large Signal Voltage Gain | A _{vOL} | R _L = 2KΩ, V _O = ±10V -55°C ≤ T _A ≤ 125°C, R _L = 2KΩ, V _O = ±10V | 10K | 15K | | V/V |
| Common Mode Rejection Ratio | CMRR | -55°C ≤ T _A ≤ 125°C, V _{cm} = ±10V | 7.5K | 90 | | dB |
| Unity Gain Bandwidth Product | GBW | A _v > 10 | | 12 | | MHz |
| Output Characteristics | | | | | | |
| Output Voltage Swing | V _O | -55°C ≤ T _A ≤ 125°C, R _L = 2KΩ | ±10.0 | ±12.0 | | V |
| Output Current | I _{OUT} | V _O = ±10V | ±10 | ±20 | | mA |
| Full Power Bandwidth | FPBW | V _O = ±10V, FPBW = (SR) (2π V _O) ⁻¹ | 750 | 1000 | | KHz |
| Transient Response | | | | | | |
| Rise Time | t _r | R _L = 2KΩ, C _L = 50pF, V _O = ±200mV | | 25 | 50 | nS |
| Overshoot | γ | R _L = 2KΩ, C _L = 50pF, V _O = ±200mV | | 25 | 40 | % |
| Slew Rate | SR | R _L = 2KΩ, C _L = 50pF, V _O = ±5V | 50 | 65 | | V/S |
| Settling Time to 0.1% | t _s | R _L = 2KΩ, C _L = 50pF, V _O = ±5V | | 0.25 | | S |
| Power Supply | | | | | | |
| Supply Current | I _S | | | 4 | 6 | mA |
| Power Supply Rejection Ratio | PSRR | -55°C ≤ T _A ≤ 125°C | 80 | 90 | | dB |

SP-2510/12/15

High Slew Rate Operational Amplifiers

Absolute Maximum Ratings

| | | | |
|---|--------|-----------------------------|--------------------------------|
| Voltage Between V ⁺ and V ⁻ Terminals | 40.0V | Operating Temperature Range | |
| Differential Input Voltage, V _d | ±15.0V | SP-2512 | -55°C ≤ T _A ≤ 125°C |
| Internal Power Dissipation, P _d | 300mW | Storage Temperature Range | -65°C ≤ T _A ≤ 150°C |
| Peak Output Current, I _p | 50mA | | |

Electrical Characteristics: V⁺ = +15V, V⁻ = -15V, T_A = 25°C unless otherwise specified in "Conditions".

SP-2512

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|---------------------------------|----------------------|--|------------|-------|-----|------------|
| Input Characteristics | | | | | | |
| Offset Voltage | V _{OS} | -55°C ≤ T _A ≤ 125°C | | 5 | 10 | mV |
| Offset Voltage Drift | ΔV _{OS} /ΔT | -55°C ≤ T _A ≤ 125°C; average | | 25 | 14 | μV/°C |
| Bias Current | I _B | -55°C ≤ T _A ≤ 125°C | | 125 | 250 | nA |
| Offset Current | I _{OS} | -55°C ≤ T _A ≤ 125°C | | 20 | 50 | nA |
| Input Impedance | Z _{in} | Guaranteed by Design | 40 | 100 | 100 | MΩ |
| Common Mode Range | V _{cm} | -55°C ≤ T _A ≤ 125°C | ±10.0 | | | V |
| Transfer Characteristics | | | | | | |
| Large Signal Voltage Gain | A _{vOL} | R _L = 2KΩ, V _O = ±10V -55°C ≤ T _A ≤ 125°C, R _L = 2KΩ, V _O = ±10V | 7.5K 5K | 15K | | V/V V/V |
| Common Mode Rejection Ratio | CMRR | -55°C ≤ T _A ≤ 125°C, V _{cm} = ±10V | 74 | 90 | | dB |
| Unity Gain Bandwidth Product | GBW | A _v > 10 | | 12 | | MHz |
| Output Characteristics | | | | | | |
| Output Voltage Swing | V _O | -55°C ≤ T _A ≤ 125°C, R _L = 2KΩ | ±10.0 | ±12.0 | | V |
| Output Current | I _{OUT} | V _O = ±10V | ±10 | ±20 | | mA |
| Full Power Bandwidth | FPBW | V _O = ±10V, FPBW = (SR) (2π V _p) ⁻¹ | 600 | 1000 | | KHz |
| Transient Response | | | | | | |
| Rise Time | t _r | R _L = 2KΩ, C _L = 50pF, V _O = ±200mV | | 25 | 50 | nS |
| Overshoot | γ | R _L = 2KΩ, C _L = 50pF, V _O = ±200mV | | 25 | 50 | % |
| Slew Rate | SR | R _L = 2KΩ, C _L = 50pF, V _O = ±5V | 40 | 60 | | V/S |
| Settling Time to 0.1% | t _s | R _L = 2KΩ, C _L = 50pF, V _O = ±5V | | 0.25 | | S |
| Power Supply | | | | | | |
| Supply Current | I _S | | | 4 | 6 | mA |
| Power Supply Rejection Ratio | PSRR | -55°C ≤ T _A ≤ 125°C | 74 | 90 | | dB |

SP-2510/12/15

High Slew Rate Operational Amplifiers

Absolute Maximum Ratings

| | | | |
|---|-------------|-----------------------------|---|
| Voltage Between V^+ and V^- Terminals | 40.0V | Operating Temperature Range | |
| Differential Input Voltage, V_d | $\pm 15.0V$ | SP-2515 | $0^\circ C \leq T_A \leq 75^\circ C$ |
| Internal Power Dissipation, P_d | 300mW | Storage Temperature Range | $-65^\circ C \leq T_A \leq 150^\circ C$ |
| Peak Output Current, I_p | 50mA | | |

Electrical Characteristics: $V^+ = +15V$, $V^- = -15V$, $T_A = 25^\circ C$ unless otherwise specified in "Conditions".

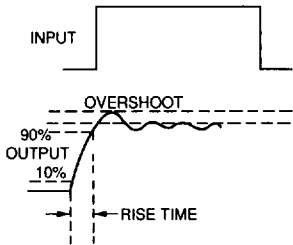
SP-2515

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|---------------------------------|--------------------------|---|------------|------------|-----|------------------|
| <u>Input Characteristics</u> | | | | | | |
| Offset Voltage | V_{os} | $0^\circ C \leq T_A \leq 75^\circ C$ | | 5 | 10 | mV |
| Offset Voltage Drift | $\Delta V_{os}/\Delta T$ | $0^\circ C \leq T_A \leq 75^\circ C$; average | | 30 | 14 | $\mu V/^\circ C$ |
| Bias Current | I_b | $0^\circ C \leq T_A \leq 75^\circ C$ | | 125 | 250 | nA |
| Offset Current | I_{os} | $0^\circ C \leq T_A \leq 75^\circ C$ | | 20 | 50 | nA |
| Input Impedance | Z_{in} | Guaranteed by Design | 40 | 100 | 100 | $M\Omega$ |
| Common Mode Range | V_{cm} | $0^\circ C \leq T_A \leq 75^\circ C$ | ± 10.0 | | | V |
| <u>Transfer Characteristics</u> | | | | | | |
| Large Signal Voltage Gain | $A_{v_{OL}}$ | $R_L = 2K\Omega$, $V_o = \pm 10V$ $0^\circ C \leq T_A \leq 75^\circ C$, $R_L = 2K\Omega$, $V_o = \pm 10V$ | 7.5K | 15K | | V/V |
| Common Mode Rejection Ratio | CMRR | $0^\circ C \leq T_A \leq 75^\circ C$, $V_{cm} = \pm 10V$ | 74 | 90 | | dB |
| Unity Gain Bandwidth Product | GBW | $A_v > 10$ | | 12 | | MHz |
| <u>Output Characteristics</u> | | | | | | |
| Output Voltage Swing | V_o | $0^\circ C \leq T_A \leq 75^\circ C$, $R_L = 2K\Omega$ | ± 10.0 | ± 12.0 | | V |
| Output Current | I_{out} | $V_o = \pm 10V$ | ± 10 | ± 20 | | mA |
| Full Power Bandwidth | FPBW | $V_o = \pm 10V$, $FPBW = (SR) (2\pi V_o)^{-1}$ | 600 | 1000 | | KHz |
| <u>Transient Response</u> | | | | | | |
| Rise Time | t_r | $R_L = 2K\Omega$, $C_L = 50pF$, $V_o = \pm 200mV$ | | 25 | 50 | nS |
| Overshoot | γ | $R_L = 2K\Omega$, $C_L = 50pF$, $V_o = \pm 200mV$ | | 25 | 50 | % |
| Slew Rate | SR | $R_L = 2K\Omega$, $C_L = 50pF$, $V_o = \pm 5V$ | 40 | 60 | | V/S |
| Settling Time to 0.1% | t_s | $R_L = 2K\Omega$, $C_L = 50pF$, $V_o = \pm 5V$ | | 0.25 | | S |
| <u>Power Supply</u> | | | | | | |
| Supply Current | I_s | | | 4 | 6 | mA |
| Power Supply Rejection Ratio | PSRR | $0^\circ C \leq T_A \leq 75^\circ C$ | 74 | 90 | | dB |

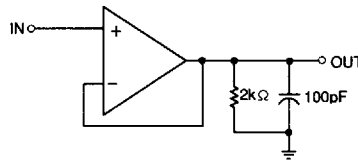
SP-2510/12/15

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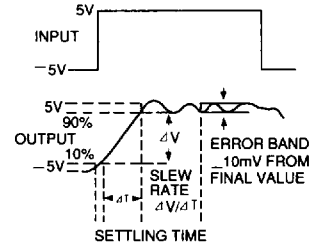
A.C. Performance



Transient Response



A.C. Test Circuit



Slew Rate/Settling Time

4

Ordering Information

When ordering the SP-2510/12/15, specify the package and screening according to the following :

| | |
|------------------------|---|
| SP 2 - 2510 - 2 | |
| Prefix: _____ | Generic Part # _____ |
| SP (SIPEX) | |
| PACKAGE : _____ | SCREENING _____ |
| 1 - 14 pin ceramic DIP | -2 : -55 °C to 125 °C |
| 2 - Metal Can | -4 : -25 °C to 85 °C |
| 3 - 8 Pin Plastic DIP | -5 : 0 °C to 75 °C |
| 4 - 20 Pin LCC | -6 : 25 °C 100% D.C. Probe (Dice Only) |
| 7 - 8-Pin Cerdip | /883 : -55 °C to 125 °C Full Mil Processing |
| 0 - DICE | |

NOTES: 1. Not all package types and screening option combinations are available. Consult local sales office or factory for availability information.

2. Consult factory for special package or screening requirements.
3. Consult factory for 883 revision C compliant data sheet.
4. Consult factory for package mechanical dimensions.

